

## FEP16AT - FEP16JT

# PIN 1 O + O CASE PIN 2 Positive CT

PIN 1 O

### **Features**

- Low forward voltage drop.
- High surge current capacity.
- High current capability.
- High reliability.

• Average Forward Current Rating at 16A (8A per Diode).





## Fast Rectifiers (Glass Passivated)

## Absolute Maximum Ratings\* T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value								Units
		16AT	16BT	16CT	16DT	16FT	16GT	16HT	16JT	1
$V_{RRM}$	Maximum Repetitive Reverse Voltage	50	100	150	200	300	400	500	600	V
I <sub>F(AV)</sub>	Average Rectified Forward Current, .375 " lead length @ T <sub>A</sub> = 100°C	· I		,	Α					
I <sub>FSM</sub>	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave	200			А					
T <sub>sta</sub>	Storage Temperature Range	emperature Range -55 to +150		°C						
T <sub>J</sub>	Operating Junction Temperature	-55 to +150			°C					

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

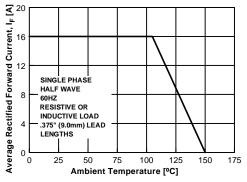
## **Thermal Characteristics**

Symbol	Parameter	Value	Units
$P_D$	Power Dissipation	8.33	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	15	°C/W
$R_{\theta JL}$	Thermal Resistance, Junction to Lead	2.2	°C/W

## **Electrical Characteristics** T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Device							Units
		16AT	16BT	16CT	16DT	16FT	16GT	16HT	16JT
V <sub>F</sub>	Forward Voltage @ 8.0A	0.95		1.3		1.5		V	
t <sub>rr</sub>	Reverse Recovery Time $I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{RR} = 0.25 \text{ A}$		35			50			ns
I <sub>R</sub>	Reverse Current @ rated $V_R$ $T_A = 25^{\circ}C$ $T_A = 100^{\circ}C$	10 500			μΑ μΑ				
Ст	Total Capacitance V <sub>R</sub> = 4.0. f = 1.0 MHz	85 60		0	pF				

## **Typical Characteristics**



**Figure 1. Forward Current Derating Curve** 

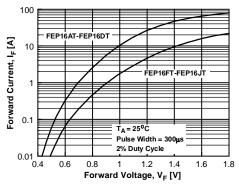


Figure 3. Forward Voltage Characteristics

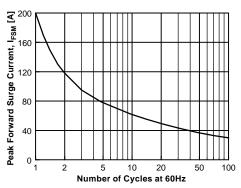


Figure 2. Non-Repetitive Surge Current Reverse Characteristics

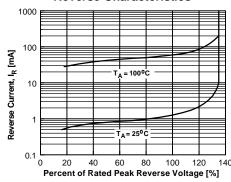


Figure 4. Reverse Current vs Reverse Voltage

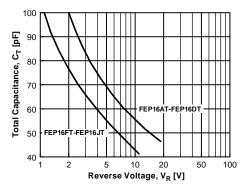
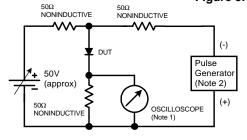
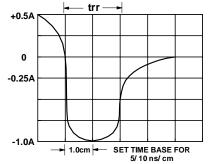


Figure 5. Total Capacitance





**Reverse Recovery Time Characterstic and Test Circuit Diagram** 

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